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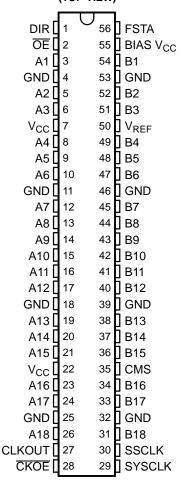
SN74GTLPH16927 18-BIT LVTTL-TO-GTLP BUS TRANSCEIVER WITH SOURCE-SYNCHRONOUS CLOCK OUTPUTS

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FEATURES

- Member of the Texas Instruments Widebus™
 Family
- TI-OPC[™] Circuitry Limits Ringing on Unevenly Loaded Backplanes
- OEC[™] Circuitry Improves Signal Integrity and Reduces Electromagnetic Interference
- Bidirectional Interface Between GTLP Signal Levels and LVTTL Logic Levels
- GTLP Buffered SYSCLK Signal (SSCLK) for Source-Synchronous Applications
- LVTTL Interfaces Are 5-V Tolerant
- Medium-Drive GTLP Outputs (50 mA)
- LVTTL Outputs (–24 mA/24 mA)
- GTLP Rise and Fall Times Designed for Optimal Data-Transfer Rate and Signal Integrity in Distributed Loads
- I_{off}, Power-Up 3-State, and BIAS V_{CC} Support Live Insertion
- Bus Hold on A-Port Data Inputs
- Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DGG OR DGV PACKAGE (TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

The SN74GTLPH16927 is a medium-drive, 18-bit bus transceiver that provides LVTTL-to-GTLP and GTLP-to-LVTTL signal-level translation. The device allows for transparent and latched modes of data transfer. Additionally, with the use of the clock-mode select (CMS) input, the device can be used in source-synchronous and clock-synchronous applications. Source-synchronous applications require the skew between the clock output and data output to be minimized for optimum maximum-frequency system performance. In order to reduce this skew, a flexible setup-time adjustment (FSTA) feature is incorporated into the device that sets a predetermined delay between the clock and data. The CMS and direction (DIR) inputs control the mode of the device.

ORDERING INFORMATION

| T _A | PACE | (AGE ⁽¹⁾ | ORDERABLE PART NUMBER | TOP-SIDE MARKING | |
|----------------|-------------|---------------------|-----------------------|------------------|--|
| l | TSSOP - DGG | Tape and reel | SN74GTLPH16927GR | GTLPH16927 | |
| –40°C to 85°C | TVSOP - DGV | Tape and reel | SN74GTLPH16927VR | GL927 | |
| | VFBGA – GQL | Tape and reel | SN74GTLPH16927KR | GL927 | |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The system clock (SYSCLK) and CLKOUT pins are LVTTL compatible, while the source-synchronous I/O is GTLP compatible. The benefits include compensation for output-to-output skew coming from the driver itself, and compensation for process skew if more than one driver is used. The device provides a high-speed interface between cards operating at LVTTL logic levels and a backplane operating at GTLP signal levels. High-speed (about three times faster than standard TTL or LVTTL) backplane operation is a direct result of GTLP's reduced output swing (<1 V), reduced input threshold levels, improved differential input, OECTM circuitry, and TI-OPCTM circuitry. Improved GTLP OEC and TI-OPC circuits minimize bus-settling time and have been designed and tested using several backplane models. The medium drive allows incident-wave switching in heavily loaded backplanes with equivalent load impedance down to 11 Ω.

GTLP is the Texas Instruments derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD 8-3. The ac specification of the SN74GTLPH16927 is given only at the preferred higher noise-margin GTLP, but the user has the flexibility of using this device at either GTL ($V_{TT} = 1.2 \text{ V}$ and $V_{REF} = 0.8 \text{ V}$) or GTLP ($V_{TT} = 1.5 \text{ V}$ and $V_{REF} = 1 \text{ V}$) signal levels. For information on using GTLP devices in FB+/BTL applications, refer to TI application reports, Texas Instruments GTLP Frequently Asked Questions, literature number SCEA019, and GTLP in BTL Applications, literature number SCEA017.

Normally, the B port operates at GTLP signal levels. The A-port and control inputs operate at LVTTL logic levels, but are 5-V tolerant and are compatible with TTL and 5-V CMOS inputs. V_{REF} is the B-port differential input reference voltage.

This device is fully specified for live-insertion applications using I_{off} , power-up 3-state, and BIAS V_{CC} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict. The BIAS V_{CC} circuitry precharges and preconditions the B-port input/output connections, preventing disturbance of active data on the backplane during card insertion or removal, and permits true live-insertion capability.

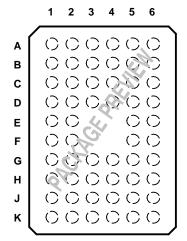
This GTLP device features TI-OPC circuitry, which actively limits the overshoot caused by improperly terminated backplanes, unevenly distributed cards, or empty slots during low-to-high signal transitions. This improves signal integrity, which allows adequate noise margin to be maintained at higher frequencies.

Active bus-hold circuitry holds unused or undriven LVTTL data inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, the output-enable (\overline{OE}) input should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

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GQL PACKAGE (TOP VIEW)



TERMINAL ASSIGNMENTS

| | 1 | 2 | 3 | 4 | 5 | 6 |
|---|-----|--------|----------|-----------|----------------------|-----|
| Α | A1 | ŌĒ | DIR | FSTA | BIAS V _{CC} | B1 |
| В | А3 | A2 | GND | GND | B2 | В3 |
| С | A5 | A4 | V_{CC} | V_{REF} | B4 | B5 |
| D | A7 | A6 | GND | GND | В6 | В7 |
| E | A9 | A8 | | | B8 | В9 |
| F | A10 | A11 | | | B11 | B10 |
| G | A12 | A13 | GND | GND | B13 | B12 |
| Н | A14 | A15 | V_{CC} | CMS | B15 | B14 |
| J | A16 | A17 | GND | GND | B17 | B16 |
| K | A18 | CLKOUT | CKOE | SYSCLK | SSCLK | B18 |

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FUNCTIONAL DESCRIPTION

The SN74GTLPH16927 is a medium-drive (50 mA), 18-bit bus transceiver containing D-type latches and D-type flip-flops for data-path operation in transparent or latched modes and can replace any of the functions shown in Table 1. Data polarity is noninverting.

Table 1. SN74GTLPH16927 Bus-Transceiver Replacement Functions

| FUNCTION | 8 BIT | 9 BIT | 10 BIT | 16 BIT | 18 BIT | | | | |
|---------------------|---|-------|--------|------------------------|--------|--|--|--|--|
| Transceiver | '245, '623, '645 | '863 | '861 | '16245, '16623 | '16863 | | | | |
| Buffer/driver | '241, '244, '541 | | '827 | '16241, '16244, '16541 | '16825 | | | | |
| Latched transceiver | '543 | | | '16543 | '16472 | | | | |
| Latch | '373, '573 | '843 | '841 | '16373 | '16843 | | | | |
| SN740 | SN74GTLPH16927 bus transceiver replaces all above functions | | | | | | | | |

Additionally, the device allows for conversion of the system clock (SYSCLK) to GTLP signal levels (SSCLK) and LVTTL signal levels (CLKOUT). It also provides conversion of a GTLP source-synchronous clock to LVTTL signal levels (CLKOUT).

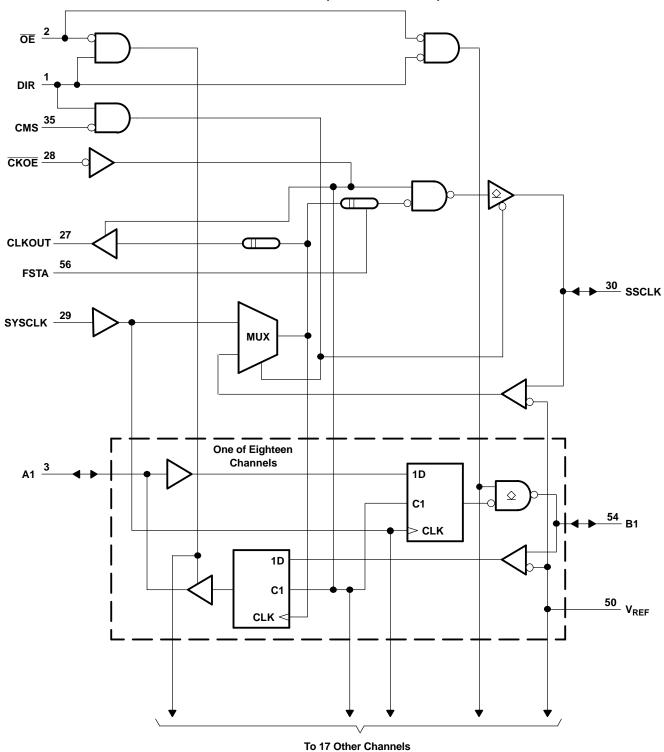
The device allows for conversion of the LVTTL system clock (SYSCLK) to GTLP (SSCLK) and LVTTL (CLKOUT) signal levels when used as the transmitter and GTLP source-synchronous clock (SSCLK) to LVTTL (CLKOUT) signal levels when used as the receiver in source-synchronous applications. Source-synchronous operation removes time-of-flight restrictions and allows for increased data throughput. CMS is used to switch between system-synchronous mode and clock-synchronous mode. The clock output-enable (CKOE) input is used to switch between latched and transparent mode.

Data flow in each direction is controlled by $\overline{\text{CKOE}}$, clock (SYSCLK or SSCLK), DIR, and $\overline{\text{OE}}$. $\overline{\text{OE}}$ controls the 18 bits of data. The CLKOUT/SSCLK buffered clock path for the A-to-B and B-to-A directions is controlled by $\overline{\text{CKOE}}$. In the data-isolation mode ($\overline{\text{OE}}$ high, $\overline{\text{CKOE}}$ low), A data can be stored in one register and/or B data can be stored in the other register.



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LOGIC DIAGRAM (POSITIVE LOGIC)(1)



(1) Pin numbers shown are for the DGG and DGV packages.





FUNCTION TABLES

A-TO-B DIRECTION

| | | INP | UTS | | | | OUTPUTS | | MODE | |
|------|----|-----|-----|------------|---|--------|---------|----------------|----------------------|-----------------------|
| CKOE | ŌĒ | CMS | DIR | SYSCLK | Α | SSCLK | CLKOUT | В | MODE | : |
| L | L | X | L | H or L | X | SYSCLK | SYSCLK | B ₁ | Latched storage of A | |
| L | L | Х | L | ↑ | L | SYSCLK | SYSCLK | L | Clasked storage of A | Source synchronous |
| L | L | X | L | \uparrow | Н | SYSCLK | SYSCLK | Н | Clocked storage of A | |
| L | Н | X | L | Χ | X | SYSCLK | SYSCLK | Z | Data isolation | |
| Н | L | X | L | Χ | L | Z | Z | L | Transparent trans | mission of A |
| Н | L | X | L | Χ | Н | Z | Z | Н | Transparent trans | mission of A |
| Н | Н | Х | Х | Х | Х | Z | Z | Z | Isolatio | n |
| L | Н | Н | Х | ↑ | Х | SYSCLK | SYSCLK | Z | Transmit SYSCLK | |
| L | Н | Н | Х | H or L | Χ | SYSCLK | SYSCLK | Z | Transmit St | SCLK |

B-TO-A DIRECTION

| | | | INPU | гѕ | | | (| DUTPUTS | | MODE | |
|------|----|-----|------|------------|------------|---|--------|---------|----------------|----------------------|-----------------------|
| CKOE | OE | CMS | DIR | SYSCLK | SSCLK | В | SSCLK | CLKOUT | Α | MODE | |
| L | L | L | Н | Х | H or L | Χ | Input | SSCLK | A ₁ | Latched storage of B | _ |
| L | L | L | Н | Х | 1 | L | Input | SSCLK | L | Clasked starage of D | Source synchronous |
| L | L | L | Н | Χ | \uparrow | Н | Input | SSCLK | Н | Clocked storage of B | - cynonionous |
| L | Н | L | Н | Х | Х | Х | Input | SSCLK | Z | Data isolation | |
| L | L | Н | Н | H or L | Output | Χ | SYSCLK | SYSCLK | A_1 | Latched storage of B | Clock synchronous |
| L | L | Н | Н | ↑ | Output | L | SYSCLK | SYSCLK | L | Clocked storage of P | |
| L | L | Н | Н | \uparrow | Output | Н | SYSCLK | SYSCLK | Н | Clocked storage of B | - cynonionous |
| L | Н | Н | Н | Х | Output | Х | SYSCLK | SYSCLK | Z | Data isola | tion |
| Н | L | Х | Н | Χ | Output | L | Z | Z | L | Transparent transp | mission of P |
| Н | L | Χ | Н | X | Output | Н | Z | Z | Н | Transparent transr | HISSION OF B |
| Н | Н | Х | Χ | Х | Output | Х | Z | Z | Z | Isolation | า |
| L | Н | L | Χ | Х | 1 | Х | Input | SSCLK | Z | Receive SSCLK | |
| L | Н | L | Χ | Χ | H or L | Χ | Input | SSCLK | Z | Receive 53 | OCLN |



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT | |
|---|--|-----------------------------|------|------|------|--|
| V _{CC} BIAS V _{CC} | Supply voltage range | | -0.5 | 4.6 | V | |
| V | In a control to the men and (2) | A-port and control inputs | -0.5 | 7 | V | |
| V _I | Input voltage range ⁽²⁾ | B port and V _{REF} | -0.5 | 4.6 | V | |
| M | Voltage range applied to any output in the | A port | -0.5 | 7 | V | |
| V _O | high-impedance or power-off state (2) | B port | -0.5 | 4.6 | V | |
| | Ourse at interness and and in the law state | A port | | 48 | Λ | |
| l _O | Current into any output in the low state | B port | | 100 | mA | |
| Io | Current into any A-port output in the high state | (3) | | 48 | mA | |
| | Continuous current through each V _{CC} or GND | | | ±100 | mA | |
| I _{IK} | Input clamp current | V _I < 0 | | -50 | mA | |
| I _{OK} | Output clamp current | V _O < 0 | | -50 | mA | |
| | | DGG package | | 64 | | |
| θ_{JA} | Package thermal impedance (4) | DGV package | | 48 | | |
| | | GQL package | | 42 | | |
| T _{stg} | Storage temperature range | | -65 | 150 | °C | |

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

This current flows only when the output is in the high state and $V_{\rm O} > V_{\rm CC}$. The package thermal impedance is calculated in accordance with JESD 51-7.





Recommended Operating Conditions (1)(2)(3)(4)

| | | | MIN | NOM | MAX | UNIT | |
|---|------------------------------------|--------------------------------|-------------------------|-----------------|-------------------------|--------|--|
| V _{CC} BIAS V _{CC} | Supply voltage | | 3.15 | 3.3 | 3.45 | V | |
| V | Tormination valtage | GTL | 1.14 | 1.2 | 1.26 | V | |
| V_{TT} | Termination voltage | GTLP | 1.35 | 1.5 | 1.65 | V | |
| V | Defended welleng | GTL | 0.74 | 0.8 | 0.87 | | |
| V_{REF} | Reference voltage | GTLP | 0.87 | 1 | 1.1 | V | |
| V | la marta contra ma | B port and SSCLK | | | V _{TT} | V | |
| V _I | Input voltage | Except B port and SSCLK | | V _{CC} | 5.5 | V | |
| V | High level inner college | B port and SSCLK | V _{REF} + 0.05 | | | V | |
| V_{IH} | High-level input voltage | Except B port, FSTA, and SSCLK | 2 | | | V | |
| V | Lave lavel inner treatment | B port and SSCLK | | | V _{REF} - 0.05 | 0.05 V | |
| V_{IL} | Low-level input voltage | Except B port, FSTA, and SSCLK | | | 0.8 | V | |
| I _{IK} | Input clamp current | | | | -18 | mA | |
| I _{OH} | High-level output current | A port and CLKOUT | | | -24 | mA | |
| | Landard and | A port and CLKOUT | | | 24 | ^ | |
| I _{OL} | Low-level output current | B port and SSCLK | | 50 | | mA | |
| Δt/Δν | Input transition rise or fall rate | Outputs enabled | | | 10 | ns/V | |
| Δt/ΔV _{CC} | Power-up ramp rate | | 20 | | | μs/V | |
| T _A | Operating free-air temperature | | -40 | | 85 | °C | |

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

(3) V_{TT} and R_{TT} can be adjusted to accommodate backplane impedances if the dc recommended I_{OL} ratings are not exceeded.

⁽²⁾ Proper connection sequence for use of the B-port I/O precharge feature is GND and BIAS V_{CC} = 3.3 V first, I/O second, and V_{CC} = 3.3 V last, because the BIAS V_{CC} precharge circuitry is disabled when any V_{CC} pin is connected. The control and V_{REF} inputs can be connected anytime, but normally are connected during the I/O stage. If B-port precharge is not required, any connection sequence is acceptable but, generally, GND is connected first.

⁽⁴⁾ V_{REF} can be adjusted to optimize noise margins, but normally is two-thirds V_{TT}. TI-OPC circuitry is enabled in the A-to-B direction and is activated when V_{TT} > 0.7 V above V_{REF}. If operated in the A-to-B direction, V_{REF} should be set to within 0.6 V of V_{TT} to minimize current drain





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Electrical Characteristics

over recommended operating free-air temperature range for GTLP (unless otherwise noted)

| Р | ARAMETER | TEST CONDITIONS | | MIN TYP | O ⁽¹⁾ MAX | UNIT |
|----------------------------------|---------------------------|---|-------------------------------------|-----------------------|----------------------|----------|
| V _{IK} | | V _{CC} = 3.15 V, | I _I = -18 mA | | -1.2 | V |
| | | V _{CC} = 3.15 V to 3.45 V, | $I_{OH} = -100 \mu A$ | V _{CC} - 0.2 | | |
| V_{OH} | A port and CLKOUT | V 0.45.V | $I_{OH} = -12 \text{ mA}$ | 2.4 | | V |
| | OLINOOT | V _{CC} = 3.15 V | $I_{OH} = -24 \text{ mA}$ | 2 | | |
| | | V _{CC} = 3.15 V to 3.45 V, | I _{OL} = 100 μA | | 0.2 | |
| | A port and CLKOUT | V 0.45 V | I _{OL} = 12 mA | | 0.4 | |
| | OLINOOT | V _{CC} = 3.15 V | I _{OL} = 24 mA | | 0.5 | |
| V_{OL} | | V _{CC} = 3.15 V to 3.45 V, | I _{OL} = 100 μA | | 0.2 | V |
| | B port and | | I _{OL} = 10 mA | | 0.2 | |
| | SŚCLK | V _{CC} = 3.15 V | $I_{OL} = 40 \text{ mA}$ | | 0.4 | |
| | | | $I_{OL} = 50 \text{ mA}$ | | 0.55 | |
| I _I | SYSCLK and control inputs | V _{CC} = 3.45 V, | V _I = 0 to 5.5 V | | ±10 | μΑ |
| I _{OZ} ⁽²⁾ | B port and SSCLK | V_{CC} = 3.45 V, V_{REF} within 0.6 V of V_{TT} , | $V_0 = 0 \text{ to } 2.3 \text{ V}$ | | ±10 | μA |
| -02 | CLKOUT | V _{CC} = 3.45 V, | $V_0 = 0 \text{ to } 5.5 \text{ V}$ | | ±10 | P |
| I _{OZH} ⁽²⁾ | A port | $V_{CC} = 3.45 \text{ V},$ | $V_O = V_{CC}$ | | 10 | μΑ |
| I _{OZL} ⁽²⁾ | A port | V _{CC} = 3.45 V, | V _O = GND | | -10 | μΑ |
| I _{BHL} (3) | A port | V _{CC} = 3.15 V, | V _I = 0.8 V | 75 | | μΑ |
| I _{BHH} ⁽⁴⁾ | A port | V _{CC} = 3.15 V, | V _I = 2 V | - 75 | | μΑ |
| I _{BHLO} ⁽⁵⁾ | A port | V _{CC} = 3.45 V, | $V_I = 0$ to V_{CC} | 500 | | μΑ |
| I _{BHHO} ⁽⁶⁾ | A port | V _{CC} = 3.45 V, | $V_I = 0$ to V_{CC} | -500 | | μΑ |
| | | $V_{CC} = 3.45 \text{ V}, I_{C} = 0,$ | Outputs high | | 50 | |
| I _{CC} | A port, B port, or SSCLK | V_{L} (A-port or control input) = V_{CC} or GND, | Outputs low | | 50 | mA |
| | OOOLIK | V_1 (B port) = V_{TT} or GND | Outputs disabled | | 50 | |
| $\Delta I_{CC}^{(7)}$ | | V_{CC} = 3.45 V, One A-port or control input at Other A-port or control inputs at V_{CC} or GNI | | | 1.5 | mA |
| • | SYSCLK inputs | V _I = 3.15 V or 0 | | 3.5 5 | _ | |
| C _i | Control inputs | V _I = 3.15 V or 0 | | | 3.5 5.5 | pF |
| | A port | V _O = 3.15 V or 0 | | | 7.5 10 | |
| C_{io} | B port or SSCLK | V _O = 1.5 V or 0 | | | 9 11 | pF |
| Co | CLKOUT | V _O = 3.15 V or 0 | | | 6 7.5 | pF |

- All typical values are at $V_{CC}=3.3$ V, $T_A=25^{\circ}C$. For I/O ports, the parameter I_I includes the off-state output leakage current.
- The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL}max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL}max.
- (4) The bus-hold circuit can source at least the minimum high sustaining current at V_{IH}min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH}min.

- An external driver must source at least I_{BHLO} to switch this node from low to high.

 An external driver must sink at least I_{BHHO} to switch this node from high to low.

 This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

Hot-Insertion Specifications for A Port

over recommended operating free-air temperature range

| PARAMETER | | TEST CONDITIONS | | | | | |
|-------------------|---|--------------------------------|-----------------------------|--|-----|----|--|
| l _{off} | $V_{CC} = 0$, | BIAS $V_{CC} = 0$, | V_I or $V_O = 0$ to 5.5 V | | 10 | μΑ | |
| I _{OZPU} | $V_{CC} = 0 \text{ to } 1.5 \text{ V},$ | $V_0 = 0.5 \text{ V to 3 V},$ | OE = 0 | | ±30 | μΑ | |
| I _{OZPD} | $V_{CC} = 1.5 \text{ V to } 0,$ | $V_0 = 0.5 V \text{ to } 3 V,$ | OE = 0 | | ±30 | μΑ | |





Live-Insertion Specifications for B Port

over recommended operating free-air temperature range

| PARAMETER | | TEST CONDITIONS | | MIN | MAX | UNIT |
|---|--|--|--|------|------|------|
| l _{off} | $V_{CC} = 0$, | BIAS $V_{CC} = 0$, | V_I or $V_O = 0$ to 1.5 V | | 10 | μΑ |
| I _{OZPU} | $V_{CC} = 0 \text{ to } 1.5 \text{ V},$ | BIAS $V_{CC} = 0$, | $V_O = 0.5 \text{ V to } 1.5 \text{ V}, \overline{OE} = 0$ | | ±30 | μΑ |
| I _{OZPD} | $V_{CC} = 1.5 \text{ V to } 0,$ | BIAS $V_{CC} = 0$, | $V_O = 0.5 \text{ V to } 1.5 \text{ V}, \overline{OE} = 0$ | | ±30 | μΑ |
| I (DIAC)/) | $V_{CC} = 0 \text{ to } 3.15 \text{ V}$ | BIAS $V_{CC} = 3.15 \text{ V to } 3.45 \text{ V},$ | V_{O} (B port) = 0 to 1.5 V | | 5 | mA |
| I _{CC} (BIAS V _{CC}) | $V_{CC} = 3.15 \text{ V to } 3.45 \text{ V}$ | $V_{CC} = 3.13 \text{ V to } 3.43 \text{ V},$ | v _O (в роп) = 0 to 1.5 v | ± | 10 | μΑ |
| V _O | $V_{CC} = 0$, | BIAS $V_{CC} = 3.3 \text{ V}$, | I _O = 0 | 0.95 | 1.05 | V |
| Io | $V_{CC} = 0$, | BIAS $V_{CC} = 3.15 \text{ V to } 3.45 \text{ V},$ | V _O (B port) = 0.6 V | -1 | | μΑ |

Timing Requirements

over recommended ranges of supply voltage and operating free-air temperature, V_{TT} = 1.5 V and V_{REF} = 1 V for GTLP (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|--------------------|-----------------|-----------------------------|-----|-----|------|
| f _{clock} | Clock frequency | | | 175 | MHz |
| | Dulas duration | CKOE high | 2.8 | | |
| t _w | Pulse duration | SYSCLK or SSCLK high or low | 3.3 | | ns |
| | | A before SYSCLK↑ | 1.2 | | |
| | Catua tima | B before SYSCLK↑ or SSCLK↑ | 2.6 | | |
| t _{su} | Setup time | A before CKOE ↓ | 1.2 | | ns |
| | | B before CKOE ↓ | 2.6 | | |
| | | A after SYSCLK↑ | 0.3 | | |
| | Hold time | B after SYSCLK↑ or SSCLK↑ | 0.8 | | |
| t _h | Hold time | A after CKOE ↓ | 1.1 | | ns |
| | | B after CKOE ↓ | 0.3 | | |



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Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature, $\rm V_{TT}$ = 1.5 V and $\rm V_{REF}$ = 1 V for GTLP (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | MIN TYP(1) | MAX | UNIT |
|------------------|------------------------|-------------------------------|------------|-----|------|
| f _{max} | A | В | 175 | | MHz |
| t _{PLH} | А | В | 3.1 | 6.5 | ns |
| t _{PHL} | A | Б | 3.1 | 6.5 | 115 |
| t _{PLH} | CKOE | В | 3.6 | 7.1 | no |
| t _{PHL} | CROE | Б | 3.6 | 7.1 | ns |
| t _{PLH} | SYSCLK | В | 3.7 | 7.3 | ns |
| t _{PHL} | STOCEN | Ь | 3.7 | 7.3 | 115 |
| t _{en} | ŌĒ | В | 3.3 | 7 | ns |
| t _{dis} | OL . | D | 3.3 | 7 | 113 |
| t _r | Rise time, B and SSCL | K outputs (20% to 80%) | 2.2 | ns | |
| t _f | Fall time, B and SSCLI | SCLK outputs (80% to 20%) 1.5 | | | |
| t _{PLH} | В | А | 2 | 5.3 | ns |
| t _{PHL} | | | 2 | 5.3 | |
| t _{PLH} | СКОЕ | А | 2.5 | 5.9 | ns |
| t _{PHL} | | ^ | 2.5 | 5.9 | |
| t _{PLH} | SYSCLK | A | 2.4 | 5.9 | ns |
| t _{PHL} | OTOOLK | T . | 2.4 | 5.9 | 113 |
| t _{PLH} | SSCLK | A | 2.9 | 6.7 | ns |
| t _{PHL} | OGOLIK | T . | 2.9 | 6.7 | 113 |
| t _{PLH} | SYSCLK | CLKOUT | 3.6 | 7.5 | ns |
| t _{PHL} | STOCEN | CENCOT | 3.6 | 7.5 | 113 |
| t _{PLH} | SSCLK | CLKOUT | 4 | 8.5 | ns |
| t _{PHL} | OGOLIK | OLINOOT | 4 | 8.5 | 113 |
| t _{en} | ŌĒ | А | 2.1 | 5.8 | ne |
| t _{dis} | OL . | ^ | 2.6 | 6.9 | |
| t _{en} | CKOE | CLKOUT | 2.2 | 5.9 | ns |
| t _{dis} | CROL | OLNOUT | 1.8 | 6 | 113 |

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C





Skew Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature,

 V_{REF} = 1 V (unless otherwise noted); standard lumped loads, C_L = 30 pF for B port (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | FSTA | TEST CONDITIONS | MIN | MAX | UNIT | |
|------------------------------------|-----------------|--|-----------------|--|-----|-----|------|--|
| t _{sk(LH)} (2) | SYSCLK | В | | | | 0.5 | ns | |
| t _{sk(HL)} (2) | STOCK | Б | | | | 0.5 | 115 | |
| | | | | $V_{CC} = 3.15 \text{ V}, T = 85^{\circ}\text{C}$ | 3.4 | 4.7 | | |
| t _{sk(LH)} (2) | SYSCLK | $SSCLK \rightarrow B_n$ (see Figure 2) | GND | $V_{CC} = 3.3 \text{ V}, T = 25^{\circ}\text{C}$ | 3.2 | 4.5 | ns | |
| | | (300 1 19410 2) | | $V_{CC} = 3.45 \text{ V}, T = -40^{\circ}\text{C}$ | 3.1 | 4.4 | | |
| | | | | V _{CC} = 3.15 V, T = 85°C | 3.2 | 4.6 | ns | |
| t _{sk(HL)} ⁽²⁾ | SYSCLK | $\begin{array}{c} \text{SSCLK} \rightarrow B_n \\ \text{(see Figure 2)} \end{array}$ | GND | $V_{CC} = 3.3 \text{ V}, T = 25^{\circ}\text{C}$ | 2.8 | 4.1 | | |
| | | | | $V_{CC} = 3.45 \text{ V}, T = -40^{\circ}\text{C}$ | 2.4 | 3.7 | | |
| | SYSCLK | $\begin{array}{c} \text{SSCLK} \rightarrow B_n \\ \text{(see Figure 2)} \end{array}$ | V _{cc} | V _{CC} = 3.15 V, T = 85°C | 7.1 | 8.9 | ns | |
| $t_{sk(LH)}^{(2)}$ | | | | $V_{CC} = 3.3 \text{ V, T} = 25^{\circ}\text{C}$ | 6.6 | 8.4 | | |
| | | | | $V_{CC} = 3.45 \text{ V}, T = -40^{\circ}\text{C}$ | 6.3 | 8 | | |
| | SYSCLK | | | V _{CC} = 3.15 V, T = 85°C | 7.2 | 9 | | |
| $t_{sk(HL)}^{(2)}$ | | $SSCLK \rightarrow B_n$ (see Figure 2) | V _{CC} | $V_{CC} = 3.3 \text{ V, T} = 25^{\circ}\text{C}$ | 6.5 | 8.2 | ns | |
| , , | | (See Figure 2) | | $V_{CC} = 3.45 \text{ V}, T = -40^{\circ}\text{C}$ | 6 | 7.6 | | |
| t _{sk(t)} (2) | SYSCLK | В | | | | 1.3 | ns | |
| t _{sk(prLH)} (3) | CVCCLK | Б | | | | 1.8 | | |
| t _{sk(prHL)} (3) | SYSCLK | В | | | | 2.8 | ns | |

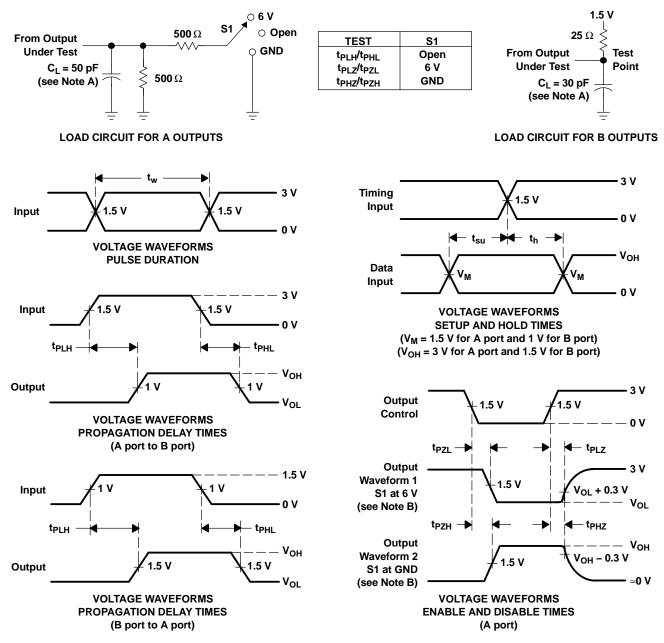
(1) Actual skew values between the GTLP outputs could vary on the backplane due to the loading and impedance seen by the device.

high and high to low [t_{sk(prLH)} or t_{sk(prHL)} – Part-to-part skew is designed as the absolute value of the difference between the actual propagation delay for all outputs from device to device. The parameter is specified for a specific worst-case V_{CC} and temperature. Furthermore, these values are provided by TI SPICE simulations.

⁽²⁾ $t_{sk(LH)}/t_{sk(HL)}$ and $t_{sk(t)}$ — Output-to-output skew is defined as the absolute value of the difference between the actual propagation delay for all outputs with the same packaged device. The specifications are given for specific worst-case V_{CC} and temperature. The specifications apply to any outputs switching in the same direction, either high to low $[t_{sk(HL)}]$, low to high $[t_{sk(LH)}]$, or in opposite directions, both low to high and high to low $[t_{sk(t)}]$.

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PARAMETER MEASUREMENT INFORMATION



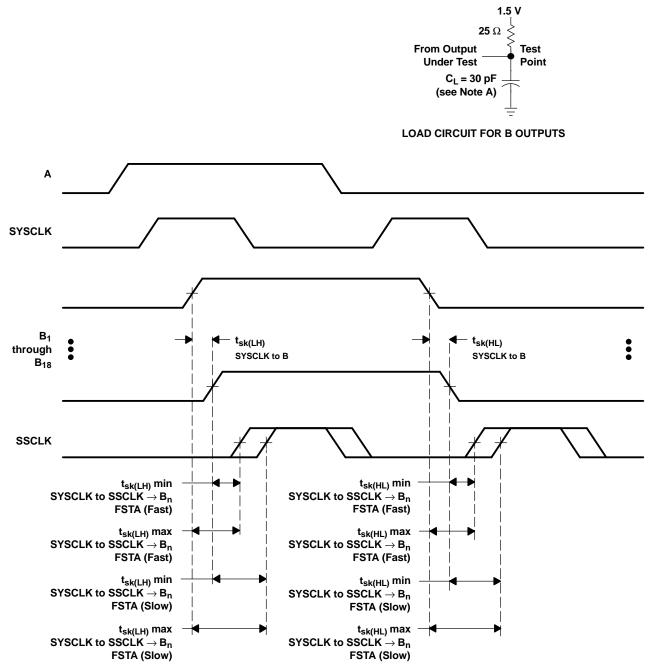
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq 2$ ns, $t_f \leq 2$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. Load circuit for A outputs also is used for CLKOUT; load circuit for B outputs also is used for SSCLK.

Figure 1. Load Circuits and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. Load circuit for B outputs also is used for SSCLK.

Figure 2. Load Circuit and SYSCLK to SSCLK \rightarrow B_n Skew Waveforms



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Distributed-Load Backplane Switching Characteristics

The preceding switching characteristics table shows the switching characteristics of the device into a lumped load (Figure 1). However, the designer's backplane application probably is a distributed load. The physical representation is shown in Figure 3. This backplane, or distributed load, can be closely approximated to a resistor inductance capacitance (RLC) circuit, as shown in Figure 4. This device has been designed for optimum performance in this RLC circuit. The following switching characteristics table shows the switching characteristics of the device into the RLC load, to help the designer to better understand the performance of the GTLP device in this typical backplane. See www.ti.com/sc/gtlp for more information.

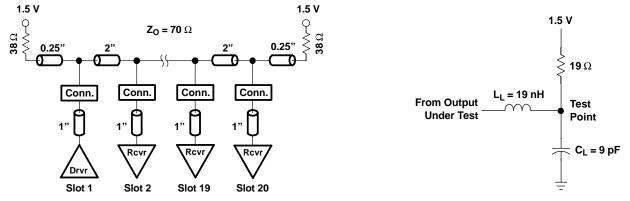


Figure 3. Medium-Drive Test Backplane

Figure 4. Medium-Drive RLC Network

Switching Characteristics

over recommended operating conditions for the bus transceiver function (unless otherwise noted) (see Figure 4)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | TYP ⁽¹⁾ | UNIT |
|------------------|------------------------|----------------|--------------------|------|
| t _{PLH} | ^ | В | 4.3 | ns |
| t _{PHL} | A | В | 4.3 | |
| t _{PLH} | SYSCLK | В | 5 | |
| t _{PHL} | STOCK | В | 5 | ns |
| t _r | Rise time, B and SSCLK | 1.2 | ns | |
| t _f | Fall time, B and SSCLK | 1.8 | ns | |

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C. All values are derived from TI SPICE models.





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PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|--------------------|-----------------------|----------------------------|--------------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| 74GTLPH16927GRE4 | ACTIVE | TSSOP | DGG | 56 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Request Free Samples |
| 74GTLPH16927GRG4 | ACTIVE | TSSOP | DGG | 56 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Request Free Samples |
| 74GTLPH16927VRE4 | ACTIVE | TVSOP | DGV | 56 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Request Free Samples |
| 74GTLPH16927VRG4 | ACTIVE | TVSOP | DGV | 56 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Request Free Samples |
| SN74GTLPH16927GR | ACTIVE | TSSOP | DGG | 56 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Request Free Samples |
| SN74GTLPH16927KR | NRND | BGA MICROSTAR JUNIOR | GQL | 56 | 1000 | TBD | SNPB | Level-1-240C-UNLIM | Samples Not Available |
| SN74GTLPH16927VR | ACTIVE | TVSOP | DGV | 56 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Request Free Samples |
| SN74GTLPH16927ZQLR | ACTIVE | BGA MICROSTAR JUNIOR | ZQL | 56 | 1000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | Purchase Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

28-Aug-2010

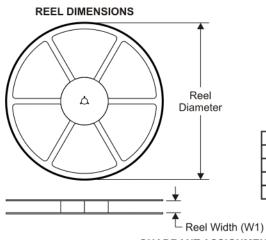
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

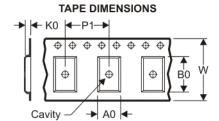
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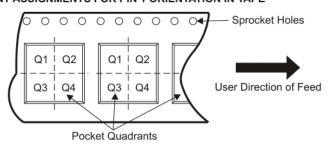
TAPE AND REEL INFORMATION





| | | Dimension designed to accommodate the component width |
|---|----|---|
| | | Dimension designed to accommodate the component length |
| F | ⟨0 | Dimension designed to accommodate the component thickness |
| | | Overall width of the carrier tape |
| Г | P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------------|----------------------------------|--------------------|----|------|--------------------------|--------------------------|---------|---------|---------|------------|-----------|------------------|
| SN74GTLPH16927GR | TSSOP | DGG | 56 | 2000 | 330.0 | 24.4 | 8.6 | 15.6 | 1.8 | 12.0 | 24.0 | Q1 |
| SN74GTLPH16927KR | BGA MI CROSTA R JUNI OR | GQL | 56 | 1000 | 330.0 | 16.4 | 4.8 | 7.3 | 1.45 | 8.0 | 16.0 | Q1 |
| SN74GTLPH16927VR | TVSOP | DGV | 56 | 2000 | 330.0 | 24.4 | 6.8 | 11.7 | 1.6 | 12.0 | 24.0 | Q1 |
| SN74GTLPH16927ZQLR | BGA MI CROSTA R JUNI OR | ZQL | 56 | 1000 | 330.0 | 16.4 | 4.8 | 7.3 | 1.45 | 8.0 | 16.0 | Q1 |



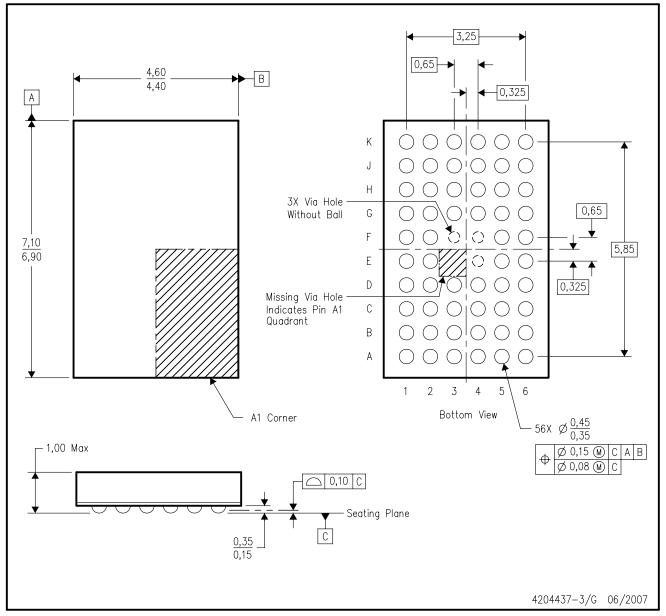


*All dimensions are nominal

| All difficultions are norminal | | | | | | | |
|--------------------------------|-------------------------|-----------------|------|------|-------------|------------|-------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| SN74GTLPH16927GR | TSSOP | DGG | 56 | 2000 | 346.0 | 346.0 | 41.0 |
| SN74GTLPH16927KR | BGA MICROSTAR JUNIOR | GQL | 56 | 1000 | 346.0 | 346.0 | 33.0 |
| SN74GTLPH16927VR | TVSOP | DGV | 56 | 2000 | 346.0 | 346.0 | 41.0 |
| SN74GTLPH16927ZQLR | BGA MICROSTAR JUNIOR | ZQL | 56 | 1000 | 346.0 | 346.0 | 33.0 |

ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

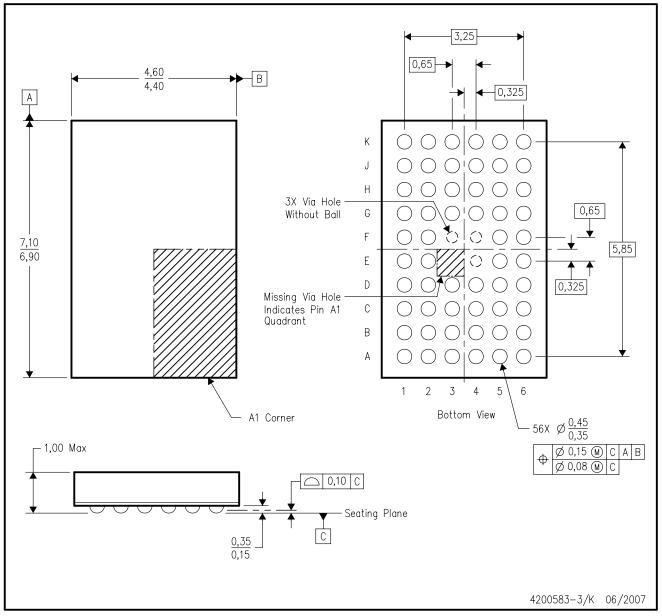
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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